EMH7 / UMH7N

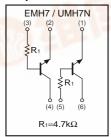
Transistors

General purpose (dual digital transistors) EMH7 / UMH7N

Features

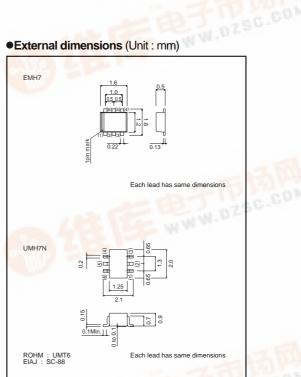
1) Two DTC143T chips in a EMT or UMT package.

Equivalent circuits



Package, marking, and packaging specifications

Туре	EMH7	UMH7N
Package	EMT6	UMT6
Marking	H7	H7
Code	TR	TR
Basic ordering unit (pieces)	8000	3000



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit			
Collector-base voltage	Vсво	50	V			
Collector-emitter voltage	Vceo	50	V			
Emitter-base voltage	VEBO	5	V			
Collector current	lc	100	mA			
Power dissipation	Pd	150(TOTAL)	mW *			
Junction temperature	Tj	150	°C			
Storage temperature	Tstg	-55 to +150	°C			

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	-	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	50		- 1	V	Ic=1mA
Emitter-base breakdown voltage	BVEBO	5	- 1	9 a-11	V	<u>Iε</u> =50μA
Collector cutoff current	Ісво			0.5	μΑ	Vcb=50V
Emitter cutoff current	ІЕВО	-	-	0.5	μΑ	V _{EB} =4V
Collector-emitter saturation voltage	VCE(sat)	- 0 - 1	-	0.3	V	Ic/I _B =5mA/0.25mA
DC current transfer ratio	hre	100	250	600	-	VcE=5V, Ic=1mA
Transition frequency	fr	-	250	-	MHz	VcE=10V, IE= -5mA, f=100MHz *
Input resistance	R ₁	3.29	4.7	6.11	kΩ	_

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*Transition frequency of the device.



•Electrical characteristics curves

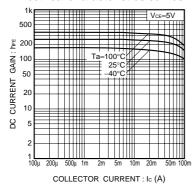


Fig.1 DC current gain vs. collector current

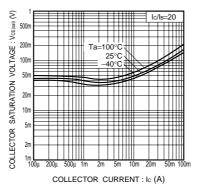


Fig.2 Collector-emitter saturation voltage vs. collector current

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